

Application Data Sheet

APPLICATION INFORMATION

Application Number::

Filing Date::

Application Type:: Regular

Subject Matter:: Utility

Suggested classification::

Suggested Group Art Unit::

CD-ROM or CD-R?: None

Number of CD Disks:

Number of Copies of CDs::

Sequence Submission?:

Computer Readable From (CRF)?: No

Number of Copies of CRF::

Title:: METHOD FOR FORMING POROUS FILM

Attorney Docket Number:: 403019

Request for Early Publication?: No

Request for Non-Publication?: No

Suggested Drawing Figure::

Total Drawing Sheets:: 5

Small Entity?: No

Latin Name::

Variety denomination name::

Petition Included?: No

Petition Type::

Licensed US Govt. Agency::

Contract or Grant Numbers::

Secrecy Order in Parent Appl.?: No

APPLICANT INFORMATION

Applicant Authority Type:: Inventor
Primary Citizenship Country:: Japan
Status:: Full Capacity
Given Name:: Kaori
Middle Name::
Family Name:: MISAWA
Name Suffix::
State or Prov. of Residence::
Country of Residence:: Japan
Street of mailing address:: c/o Semiconductor Leading Edge
Technologies, Inc., 16-1 Onogawa
City of mailing address:: Tsukuba-shi
State or Province of mailing address:: Ibaraki
Country of mailing address:: Japan
Postal or Zip Code of mailing address:: 305-8569

Inventor Authority Type:: Inventor
Primary Citizenship Country:: Japan
Status:: Full Capacity
Given Name:: Isao
Middle Name::
Family Name:: MATSUMOTO
Name Suffix::
State or Prov. of Residence::
Country of Residence:: Japan
Street of mailing address:: c/o Semiconductor Leading Edge
Technologies, Inc., 16-1 Onogawa
City of mailing address:: Tsukuba-shi
State or Province of mailing address:: Ibaraki
Country of mailing address:: Japan
Postal or Zip Code of mailing address:: 305-8569

Applicant Authority Type:: Inventor
Primary Citizenship Country:: Japan
Status:: Full Capacity
Given Name:: Naofumi
Middle Name::
Family Name:: OHASHI
Name Suffix::
State or Prov. of Residence::
Country of Residence:: Japan
Street of mailing address:: c/o Semiconductor Leading Edge
Technologies, Inc., 16-1 Onogawa
City of mailing address:: Tsukuba-shi
State or Province of mailing address:: Ibaraki
Country of mailing address:: Japan
Postal or Zip Code of mailing address:: 305-8569

Applicant Authority Type:: Inventor
Primary Citizenship Country:: Japan
Status:: Full Capacity
Given Name:: Koichi
Middle Name::
Family Name:: ABE
State or Prov. of Residence::
Country of Residence:: Japan
Street of mailing address:: c/o Hitachi Chemical Co., Ltd.
Res. & Dev. Center
13-1 Higashi-cho, 4-chome
City of mailing address:: Hitachi-shi
State or Province of mailing address:: Ibaraki
Country of mailing address:: Japan
Postal or Zip Code of mailing address:: 317-8555

Applicant Authority Type:: Inventor
Primary Citizenship Country:: Japan
Status:: Full Capacity
Given Name:: Haruaki
Middle Name::
Family Name:: SAKURAI
Name Suffix::
State or Prov. of Residence::
Country of Residence:: Japan
Street of mailing address:: c/o Hitachi Chemical Co., Ltd.
Yamazaki Works
13-1 Higashi-cho, 4-chome
City of mailing address:: Hitachi-shi
State or Province of mailing address:: Ibaraki
Country of mailing address:: Japan
Postal or Zip Code of mailing address:: 317-8555

CORRESPONDENCE INFORMATION

Correspondence Customer Number:: 23548
Phone:: (202) 737-6770
Fax:: (202) 737-6776
E-mail Address:: dcmail2@leydig.com

REPRESENTATIVE INFORMATION

Representative Customer Number:: 23548

Representative Designation:: Registration Number:: Representative Name::

DOMESTIC PRIORITY INFORMATION

Application:: Continuity Type:: Parent Application:: Parent Filing Date::

FOREIGN APPLICATION INFORMATION

Country::	Application Number::	Filing Date::	Priority Claimed
Japan	2003-099670	04/02/03	Yes

ASSIGNEE INFORMATION

Assignee name:: Semiconductor Leading Edge Technologies, Inc.

Street of mailing address:: 16-1 Onogawa

City of mailing address:: Tsukuba-shi

State or Province of
mailing address:: Ibaraki

Country of mailing
address:: Japan

Postal or Zip Code of
mailing address:: 305-8569